

Date: 1 July, 2017

To Whom It May Concern:

**RoHS Certificate of Compliance**

We certify that our microwave semiconductor products indicated below are in compliance with EU Directive 2011/65/EU on the Restriction of Hazardous Substances (RoHS).

**1. Applicable Product Type**

Toshiba Product Type	Description
TGI series	Internally Matched Power GaN HEMTs
TGM series	Power GaN Amplifier
TIM series	Internally Matched Power GaAs FETs
TMD series	GaAs MMICs
TPM series	Partially Matched Power GaAs FETs

**2. Substances and the maximum allowable concentration (Threshold level)**

Substance	Threshold level	Contained level
1) Cadmium and its compound	< 100 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
2) Lead and its compound	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
3) Hexavalent chromium and its compound	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
4) Mercury and its compound	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
5) Polybrominated biphenyls (PBBs)	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
6) Polybrominated diphenyl ethers (PBDEs)	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below

Company: Toshiba Infrastructure Systems & Solutions Corporation

Signature: 

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